

# isc Silicon NPN Darlington Power Transistor

2SD985

### **DESCRIPTION**

- · Collector-Emitter Breakdown Voltage-
  - :  $V_{(BR)CEO} = 60V(Min.)$
- DC Current Gain-
  - : h<sub>FE</sub> = 2000(Min) @ I<sub>C</sub>= 1A
- · Low Collector Saturation Voltage
- Complement to Type 2SB794
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

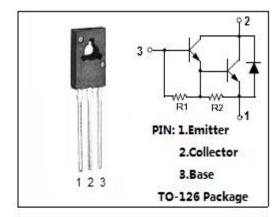


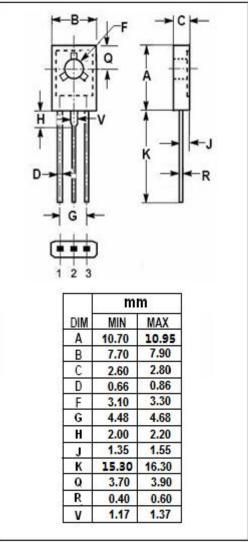
#### **APPLICATIONS**

• They are suitable for use to operate from IC without predriver, such as hammer driver.



SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	150	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	60	V	
V <sub>EBO</sub>	Emitter-Base Voltage	8	V	
Ic	Collector Current-Continuous	1.5	А	
I <sub>CM</sub>	Collector Current-Pulse	3.0	А	
I <sub>B</sub>	Base Current	0.15	Α	
Pc	Collector Power Dissipation T <sub>a</sub> =25°C	1.0	W	
	Collector Power Dissipation Tc=25 °C	10		
Ti	Junction Temperature	150	$^{\circ}$	
T <sub>stg</sub>	Storage Temperature Range	-55~150	$^{\circ}$	







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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

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SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT	
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 1A; I <sub>B</sub> = 1mA			1.5	V	
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 1A; I <sub>B</sub> = 1mA			2.0	V	
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 60V; I <sub>E</sub> = 0			10	μА	
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			1.0	mA	
h <sub>FE-1</sub>	DC Current Gain	Ic= 0.5A; V <sub>CE</sub> = 2V	1000				
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 1A; V <sub>CE</sub> = 2V	2000		30000		
Switching Times							
t <sub>on</sub>	Turn-on Time	47		0.5		μ \$	
t <sub>stg</sub>	Storage Time	$I_C$ =1.0A; $I_{B1}$ = $I_{B2}$ =1.0mA $V_{CC}$ =50V; $R_L$ =50 $Ω$		1.0		μS	
t <sub>f</sub>	Fall Time			1.0		μ <b>s</b>	

## h<sub>FE-2</sub> Classifications

M	L	К	
2000-5000	4000-10000	8000-30000	

### **NOTICE:**

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